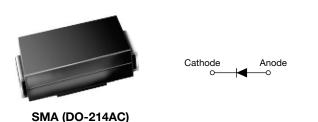
Vishay Semiconductors

Hyperfast Rectifier, 2 A FRED Pt[®]



www.vishay.com

LINKS TO ADDITIONAL RESOURCES

30 **3D Models**

PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 A				
V _R	100 V				
V _F at I _F	0.75 V				
t _{rr}	25 ns				
T _J max.	175 °C				
Package	SMA (DO-214AC)				
Circuit configuration	Single				

FEATURES

- Hyperfast recovery time, reduced Qrr, and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- · Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 gualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in snubber, boost, lighting, piezo injection, as high frequency rectifiers, and freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

MECHANICAL DATA

Case: SMA (DO-214AC)

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		100	V		
Average rectified forward current	I _{F(AV)}	T _{Sp} = 138 °C	2	٨		
Non-repetitive peak surge current	I _{FSM}	$T_J = 25 \ ^{\circ}C$, 6 ms square pulse	50	A		
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C		



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ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	100	-	-	
Forward voltage, per diode	¥-	$I_F = 2 A$	0.88	0.95	V	
	V _F	I _F = 2 A, T _J = 125 °C	-	0.75	0.82	
Reverse leakage current, per diode	I_	$V_{R} = V_{R}$ rated	-	-	2	μΑ
	I _R	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	0.6	8	
Junction capacitance	CT	V _R = 100 V	-	8.5	-	pF

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 5$	50 A/µs, V _R = 30 V	-	24	-		
Reverse recovery time	+	I _F = 0.5 A, I _R = 1 A	A, I _{rr} = 0.25 A	-	-	25	ns	
neverse recovery time	t _{rr}	T _J = 25 °C		-	16	-		
		T _J = 125 °C		-	22	-		
Deels receivers aureent	1	T _J = 25 °C	$I_F = 2 A$,	-	2	-	А	
Peak recovery current	IRRM	T _J = 125 °C	dl _F /dt = 200 A/µs, V _B = 160 V	-	3	-		
	0	0	T _J = 25 °C		-	16	-	nC
Reverse recovery charge	Q _{rr}	T _J = 125 °C	1	-	30	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Thermal resistance, junction to lead	R _{thJL}	Device mounted on PCB with 2 x 3.5 mm soldering lands	-	11	21	°C/W	
Thermal resistance, junction to ambient	R _{thJA}	Device mounted on PCB with recommended pad size	-	-	125	°C/W	
Approximate weight			0.07		g		
Approximate weight				0.002		oz.	
Marking device		Case style SMA (DO-214AC)		2	H1		



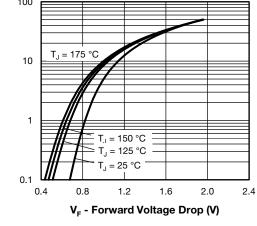
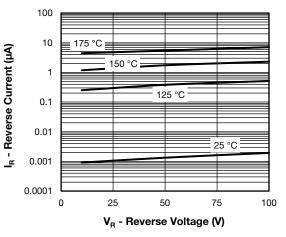
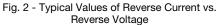


Fig. 1 - Typical Forward Voltage Drop Characteristics





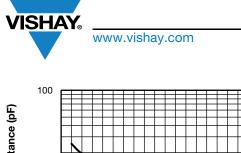
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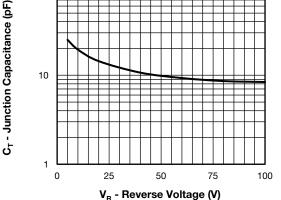


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

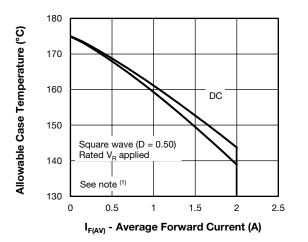


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

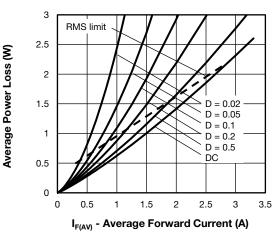


Fig. 5 - Forward Power Loss Characteristics

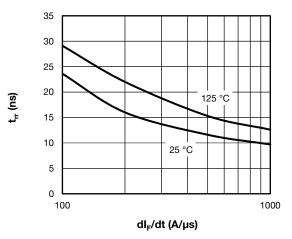


Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt

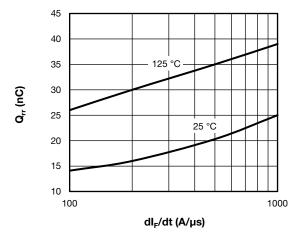


Fig. 7 - Typical Stored Charge vs. dl_F/dt

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ at \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (1 - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ at \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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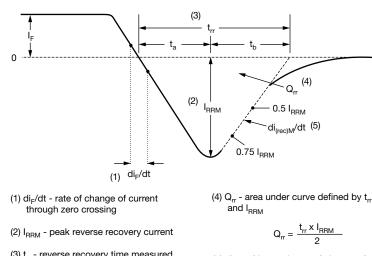
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VS-2EMH01HM3

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(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 8 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

www.vishay.com

Device code	VS-	2	Е	м	н	01	н	М3
		2	3	4	5	6	7	8
	1 -	Visl	nay Sen	nicondu	ctors pro	oduct		
	2 -	Cur	rent rati	ng (2 =	2 A)			
	3 -	Circ	uit conf	iguratio	า:			
		E =	single c	liode				
	4 -	M =	M = SMA package					
	5 -	Pro	cess typ	be,				
		H =	hyperfa	st recov	very			
	6 -	Volt	age coo	de (01 =	100 V)			
	7 -	H =	AEC-Q	101 qua	lified			
	8 -	M3	= halog	en-free,	RoHS-0	complia	nt, and	termina

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIP						
VS-2EMH01HM3/5AT	7500	7500	13"diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95400					
Part marking information	www.vishay.com/doc?95472				
Packaging information	www.vishay.com/doc?95404				
SPICE model	www.vishay.com/doc?96376				

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Outline Dimensions

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SMA

DIMENSIONS in inches (millimeters)

DO-214AC (SMA)





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